## **TJF1051**

# High-speed CAN transceiver Rev. 3 — 8 February 2013

**Product data sheet** 

#### **General description** 1.

The TJF1051 is a high-speed CAN transceiver that provides an interface between a Controller Area Network (CAN) protocol controller and the physical two-wire CAN bus. The transceiver is designed for high-speed (up to 1 Mbit/s) CAN industrial applications, providing differential transmit and receive capability to (a microcontroller with) a CAN protocol controller.

The TJF1051 belongs to the third generation of high-speed CAN transceivers from NXP Semiconductors, offering significant improvements over first- and second-generation devices such as the TJA1050. It offers improved ElectroMagnetic Compatibility (EMC) and ElectroStatic Discharge (ESD) performance, and also features ideal passive behavior to the CAN bus when the supply voltage is off.

The TJF1051T/3 can be interfaced directly to microcontrollers with supply voltages from 3 V to 5 V

These features make the TJF1051 an excellent choice for all types of HS-CAN networks, in nodes that do not require a standby mode with wake-up capability via the bus.

#### 2. **Features and benefits**

#### 2.1 General

- Fully ISO 11898-2 compliant
- Low ElectroMagnetic Emission (EME) and high ElectroMagnetic Immunity (EMI)
- V<sub>IO</sub> input on the TJF1051T/3 allows for direct interfacing with 3 V to 5 V microcontrollers

#### 2.2 Low-power management

- Functional behavior predictable under all supply conditions
- Transceiver disengages from the bus when not powered up (zero load)

#### 2.3 Protection

- High ESD handling capability on the bus pins
- Transmit Data (TXD) dominant time-out function
- Undervoltage detection on pins V<sub>CC</sub> and V<sub>IO</sub>
- Thermally protected



### High-speed CAN transceiver

## 3. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		4.5	-	5.5	V
$V_{uvd(VCC)}$	undervoltage detection voltage on pin $V_{\mbox{\footnotesize CC}}$		3.5	-	4.5	V
I <sub>CC</sub>	supply current	Silent mode	0.1	1	2.5	mA
		Normal mode; bus recessive	2.5	5	10	mA
		Normal mode; bus dominant	20	50	70	mΑ
V <sub>ESD</sub>	electrostatic discharge voltage	HBM on pins CANH and CANL	-8	-	+8	kV
$V_{CANH}$	voltage on pin CANH	no time limit; DC limiting value	-58	-	+58	V
$V_{CANL}$	voltage on pin CANL	no time limit; DC limiting value	-58	-	+58	V

## 4. Ordering information

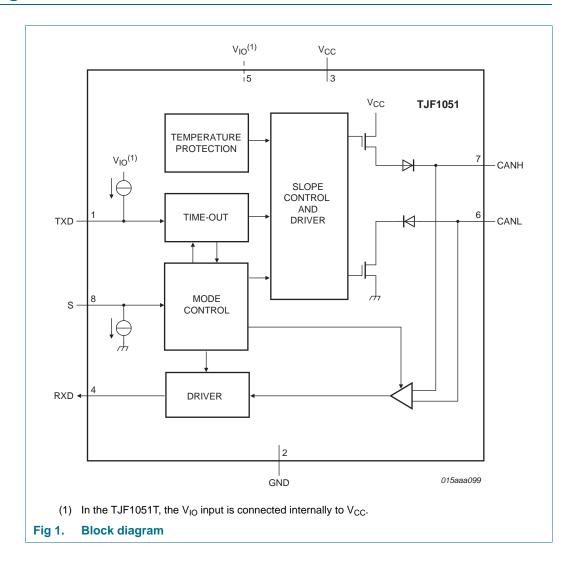
Table 2. Ordering information

Type number	Package	Package				
	Name	Description	Version			
TJF1051T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1			
TJF1051T/3[1]	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1			

<sup>[1]</sup> TJF1051T/3 with  $V_{IO}$  pin.

#### **High-speed CAN transceiver**

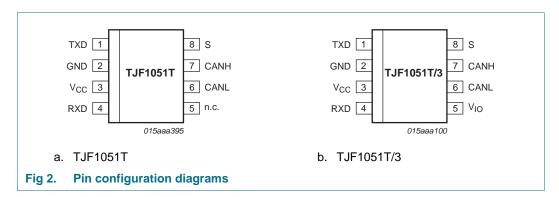
## 5. Block diagram



#### **High-speed CAN transceiver**

## 6. Pinning information

#### 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

10010 01	· ··· door.p.ioi	
Symbol	Pin	Description
TXD	1	transmit data input
GND	2	ground
$V_{CC}$	3	supply voltage
RXD	4	receive data output; reads out data from the bus lines
n.c.	5	not connected; in TJF1051T
$V_{IO}$	5	supply voltage for I/O level adapter; TJF1051T/3 only
CANL	6	LOW-level CAN bus line
CANH	7	HIGH-level CAN bus line
S	8	Silent mode control input

**High-speed CAN transceiver** 

#### 7. Functional description

The TJF1051 is a stand-alone high-speed CAN transceiver with Silent mode. It combines the functionality of the TJA1050 transceiver with improved EMC and ESD handling capability. Improved slope control and high DC handling capability on the bus pins provides additional application flexibility. The TJF1051T/3 allows for direct interfacing to microcontrollers with supply voltages down to 3 V.

#### 7.1 Operating modes

The TJF1051 supports two operating modes, Normal and Silent. The operating mode is selected via pin S. See <u>Table 4</u> for a description of the operating modes under normal supply conditions.

Table 4. Operating modes

Mode	Inputs		Outputs		
	Pin S	Pin TXD	CAN driver	Pin RXD	
Normal	LOW	LOW	dominant	active[1]	
	LOW	HIGH	recessive	active[1]	
Silent	HIGH	X[2]	recessive	active[1]	

<sup>[1]</sup> LOW if the CAN bus is dominant, HIGH if the CAN bus is recessive.

#### 7.1.1 Normal mode

A LOW level on pin S selects Normal mode. In this mode, the transceiver is able to transmit and receive data via bus lines CANH and CANL (see <u>Figure 1</u> for the block diagram). The differential receiver converts the analog data on the bus lines into digital data which is output to pin RXD. The slope of the output signals on the bus lines is controlled and optimized in a way that guarantees the lowest possible EME levels.

#### 7.1.2 Silent mode

A HIGH level on pin S selects Silent mode. In Silent mode the transmitter is disabled, releasing the bus pins to recessive state. All other IC functions, including the receiver, continue to operate as in Normal mode. Silent mode can be used to prevent a faulty CAN controller from disrupting all network communications.

#### 7.2 Fail-safe features

#### 7.2.1 TXD dominant time-out function

A 'TXD dominant time-out' timer is started when pin TXD is set LOW. If the LOW state on pin TXD persists for longer than  $t_{to(dom)TXD}$ , the transmitter is disabled, releasing the bus lines to recessive state. This function prevents a hardware and/or software application failure from driving the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out timer is reset when pin TXD is set HIGH. The TXD dominant time-out time also defines the minimum possible bit rate of 40 kbit/s.

#### 7.2.2 Internal biasing of TXD and S input pins

Pin TXD has an internal pull-up to  $V_{IO}$  and pin S has an internal pull-down to GND. This ensures a safe, defined state in case one (or both) of these pins is left floating.

TJF1051

<sup>[2]</sup> X = don't care.

#### **High-speed CAN transceiver**

#### 7.2.3 Undervoltage detection on pins $V_{CC}$ and $V_{IO}$

Should  $V_{CC}$  or  $V_{IO}$  drop below their respective undervoltage detection levels ( $V_{uvd(VCC)}$  and  $V_{uvd(VIO)}$ ; see <u>Table 7</u>), the transceiver will switch off and disengage from the bus (zero load) until  $V_{CC}$  and  $V_{IO}$  have recovered.

#### 7.2.4 Overtemperature protection

The output drivers are protected against overtemperature conditions. If the virtual junction temperature exceeds the shutdown junction temperature,  $T_{j(sd)}$ , the output drivers will be disabled until the virtual junction temperature falls below  $T_{j(sd)}$  and TXD becomes recessive again. Including the TXD condition ensures that output driver oscillations due to temperature drift are avoided.

#### **7.3** V<sub>IO</sub> supply pin (TJF1051T/3)

Pin  $V_{IO}$  on the TJF1051T/3 should be connected to the microcontroller supply voltage (see <u>Figure 5</u>). This adjusts the signal levels on pins TXD, RXD and S to the I/O levels of the microcontroller. In the TJF1051T, the  $V_{IO}$  input is internally connected to  $V_{CC}$ . This sets the signal levels of pins TXD, RXD and S to levels compatible with 5 V microcontrollers.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). All voltages are referenced to GND.

Symbol	Parameter	Conditions		Min	Max	Unit
$V_x$	voltage on pin x	no time limit; DC value				
		on pins CANH and CANL		-58	+58	V
		on any other pin		-0.3	+7	V
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	<u>[1]</u>			
		pins CANH and CANL		-8	+8	kV
		any other pin		-4	+4	kV
		MM	[2]			
		any pin		-300	+300	V
$T_{vj}$	virtual junction temperature		[3]	-40	+125	°C
T <sub>stg</sub>	storage temperature			-55	+150	°C

<sup>[1]</sup> Human Body Model (HBM): 100 pF, 1.5 k $\Omega$ .

#### 9. Thermal characteristics

Table 6. Thermal characteristics

According to IEC 60747-1.

Symbol	Parameter	Conditions	Value	Unit
$R_{th(vj-a)}$	thermal resistance from virtual junction to ambient	in free air	120	K/W
TJF1051	All information provided in this document is	subject to legal disclaimers.	© NXP B.V. 2013.	All rights reserved.

<sup>[2]</sup> Machine Model (MM): 200 pF, 0.75  $\mu$ H, 10  $\Omega$ .

<sup>[3]</sup> In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is: T<sub>vj</sub> = T<sub>amb</sub> + P × R<sub>th(vj-a)</sub>, where R<sub>th(vj-a)</sub> is a fixed value to be used for the calculation of T<sub>vj</sub>. The rating for T<sub>vj</sub> limits the allowable combinations of power dissipation (P) and ambient temperature (T<sub>amb</sub>).

#### **High-speed CAN transceiver**

## 10. Static characteristics

Table 7. Static characteristics

 $T_{amb} = -40$  °C to +105 °C;  $V_{CC} = 4.5$  V to 5.5 V;  $V_{IO} = 2.8$  V to 5.5 V $\frac{11}{2}$ ;  $R_L = 60$   $\Omega$ ; unless otherwise specified; all voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply; pir	ı V <sub>CC</sub>					
V <sub>CC</sub>	supply voltage		4.5	-	5.5	V
I <sub>CC</sub>	supply current	Silent mode	0.1	1	2.5	mA
		Normal mode				
		recessive	2.5	5	10	mΑ
		dominant; V <sub>TXD</sub> = 0 V	20	50	70	mA
$V_{uvd(VCC)}$	undervoltage detection voltage on pin $V_{\text{CC}}$		3.5	-	4.5	V
I/O level ad	apter supply; pin V <sub>IO</sub> [1]					
V <sub>IO</sub>	supply voltage on pin V <sub>IO</sub>		2.8	-	5.5	V
I <sub>IO</sub>	supply current on pin V <sub>IO</sub>	Normal and Silent modes				
		recessive; $V_{TXD} = V_{IO}$	10	80	250	μΑ
		dominant; V <sub>TXD</sub> = 0 V	50	350	500	μΑ
$V_{uvd(VIO)}$	undervoltage detection voltage on pin $V_{\text{IO}}$		1.3	-	2.7	V
Mode conti	ol input; pin S					
V <sub>IH</sub>	HIGH-level input voltage		$0.7V_{IO}$	-	$V_{10} + 0.3$	V
V <sub>IL</sub>	LOW-level input voltage		-0.3	-	+0.3V <sub>IO</sub>	V
I <sub>IH</sub>	HIGH-level input current		1	4	10	μΑ
I <sub>IL</sub>	LOW-level input current	V <sub>S</sub> = 0 V	-1	0	+1	μΑ
CAN transr	nit data input; pin TXD					
V <sub>IH</sub>	HIGH-level input voltage		$0.7V_{IO}$	-	$V_{10} + 0.3$	V
V <sub>IL</sub>	LOW-level input voltage		-0.3	-	+0.3V <sub>IO</sub>	V
I <sub>IH</sub>	HIGH-level input current	$V_{TXD} = V_{IO}$	-5	0	+5	μΑ
I <sub>IL</sub>	LOW-level input current	Normal mode; V <sub>TXD</sub> = 0 V	-260	-150	-30	μΑ
Ci	input capacitance		-	5	10	pF
CAN receiv	e data output; pin RXD					
I <sub>OH</sub>	HIGH-level output current	$V_{RXD} = V_{IO} - 0.4 V$	-8	-3	-1	mΑ
I <sub>OL</sub>	LOW-level output current	V <sub>RXD</sub> = 0.4 V; bus dominant	2	5	12	mΑ
Bus lines;	pins CANH and CANL					
$V_{O(dom)}$	dominant output voltage	$V_{TXD} = 0 V; t < t_{to(dom)TXD}$				
		pin CANH	2.75	3.5	4.5	V
		pin CANL	0.5	1.5	2.25	V
$V_{dom(TX)sym}$	transmitter dominant voltage symmetry	$V_{dom(TX)sym} = V_{CC} - V_{CANH} - V_{CANL}$	-400	0	+400	mV
V <sub>O(dif)bus</sub>	bus differential output voltage	$V_{TXD} = 0 \text{ V};  t < t_{to(dom)TXD}$	1.5	-	3	V
• •		V <sub>TXD</sub> = V <sub>IO</sub> ; recessive; no load	-50	-	+50	mV

#### **High-speed CAN transceiver**

 Table 7.
 Static characteristics ...continued

 $T_{amb} = -40$  °C to +105 °C;  $V_{CC} = 4.5$  V to 5.5 V;  $V_{IO} = 2.8$  V to 5.5 V[1];  $R_L = 60$   $\Omega$ ; unless otherwise specified; all voltages are defined with respect to ground; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>O(rec)</sub>	recessive output voltage	Normal and Silent modes; $V_{TXD} = V_{IO}$ ; no load	2	0.5V <sub>CC</sub>	3	V
$V_{th(RX)dif}$	differential receiver threshold voltage	Normal and Silent modes $V_{cm(CAN)}^{[2]} = -12 \text{ V to } +12 \text{ V}$	0.5	0.7	0.9	V
$V_{hys(RX)dif}$	differential receiver hysteresis voltage	Normal and Silent modes $V_{cm(CAN)} = -12 \text{ V to } +12 \text{ V}$	50	120	400	mV
I <sub>O(dom)</sub>	dominant output current	$V_{TXD} = 0 V$ ; $t < t_{to(dom)TXD}$ ; $V_{CC} = 5 V$				
		pin CANH; V <sub>CANH</sub> = 0 V	-120	-70	-40	mA
		pin CANL; V <sub>CANL</sub> = 5 V/40 V	40	70	120	mΑ
I <sub>O(rec)</sub>	recessive output current	Normal and Silent modes; $V_{TXD} = V_{CC}$ ; $V_{CANH} = V_{CANL} = -27 \text{ V to } +32 \text{ V}$	<b>-5</b>	-	+5	mA
IL	leakage current	$V_{CC} = 0 \text{ V}; V_{CANH} = V_{CANL} = 5 \text{ V}$	-5	0	+5	μΑ
R <sub>i</sub>	input resistance		9	15	28	kΩ
$\Delta R_i$	input resistance deviation	between V <sub>CANH</sub> and V <sub>CANL</sub>	-3	0	+3	%
R <sub>i(dif)</sub>	differential input resistance		19	30	52	kΩ
C <sub>i(cm)</sub>	common-mode input capacitance		-	-	20	pF
C <sub>i(dif)</sub>	differential input capacitance		-	-	10	pF
Temperatu	re protection					
T <sub>j(sd)</sub>	shutdown junction temperature		-	190	-	°C

<sup>[1]</sup> Only the TJF1051T/3 has a  $V_{IO}$  pin; in the TJF1051T, the  $V_{IO}$  input is internally connected to  $V_{CC}$ .

<sup>[2]</sup>  $V_{cm(CAN)}$  is the common mode voltage of CANH and CANL.

#### **High-speed CAN transceiver**

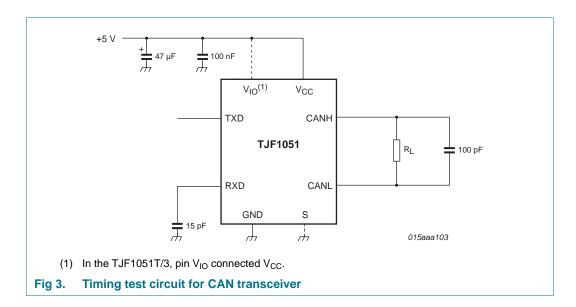
## 11. Dynamic characteristics

#### Table 8. Dynamic characteristics

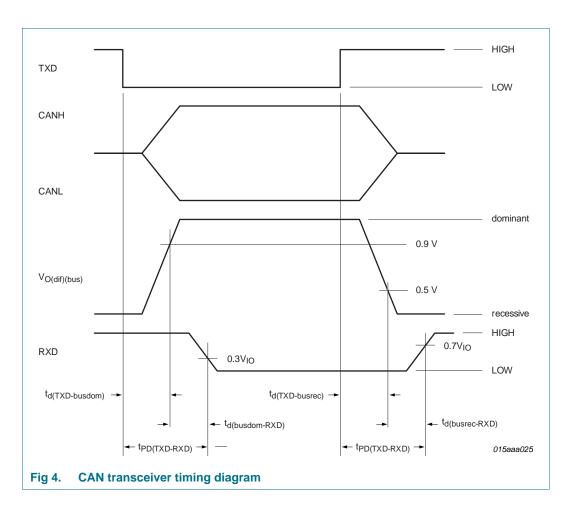
 $T_{amb} = -40$  °C to +105 °C;  $V_{CC} = 4.5$  V to 5.5 V;  $V_{IO} = 2.8$  V to 5.5 V $^{(1)}_{C}$ ;  $R_L = 60$   $\Omega$  unless specified otherwise. All voltages are defined with respect to ground. Positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
Transceiver t	Transceiver timing; pins CANH, CANL, TXD and RXD; see Figure 3 and Figure 4								
t <sub>d(TXD-busdom)</sub>	delay time from TXD to bus dominant	Normal mode	-	65	-	ns			
t <sub>d(TXD-busrec)</sub>	delay time from TXD to bus recessive	Normal mode	-	90	-	ns			
t <sub>d(busdom-RXD)</sub>	delay time from bus dominant to RXD	Normal and Silent modes	-	60	-	ns			
t <sub>d(busrec-RXD)</sub>	delay time from bus recessive to RXD	Normal and Silent modes	-	65	-	ns			
t <sub>PD(TXD-RXD)</sub>	propagation delay from TXD to RXD	2.8 V < V <sub>IO</sub> < 4.5 V Normal mode	40	-	250	ns			
		$4.5 \text{ V} > \text{V}_{\text{CC}} = \text{V}_{\text{IO}} < 5.5 \text{ V}$ Normal mode	40	-	220	ns			
t <sub>to(dom)TXD</sub>	TXD dominant time-out time	V <sub>TXD</sub> = 0 V; Normal mode	0.3	1	12	ms			

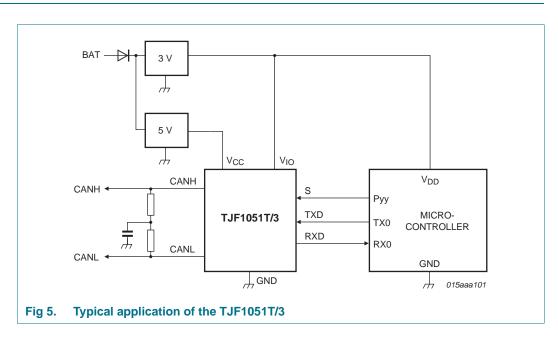
[1] Only the TJF1051T/3 has a  $V_{IO}$  pin. In the TJF1051T, the  $V_{IO}$  input is internally connected to  $V_{CC}$ .



#### **High-speed CAN transceiver**



## 12. Application information



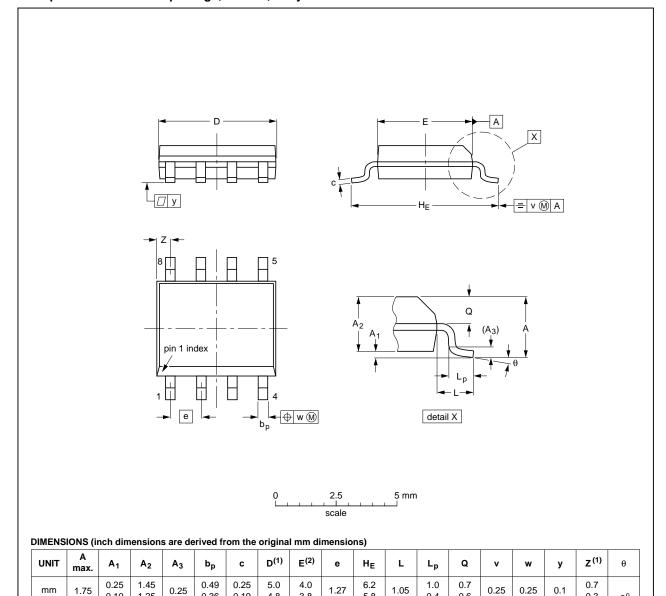
**TJF1051 NXP Semiconductors** 

#### **High-speed CAN transceiver**

## 13. Package outline

#### SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



inches

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.36

0.19

0.019 0.0100

0.014 0.0075

4.8

0.20

0.19

3.8

0.16

0.15

2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	IOOUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT96-1	076E03	MS-012				<del>99-12-27</del> 03-02-18	

0.05

5.8

0.244

0.228

0.041

0.4

0.039

0.016

0.6

0.028

0.024

Package outline SOT96-1 (SO8) Fig 6.

1.25

0.057

0.049

0.01

0.10

0.010

0.004

0.069

TJF1051

0.3

0.028

0.004

0.01

0.01

00

**High-speed CAN transceiver** 

#### 14. Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in *JESD625-A* or equivalent standards.

## 15. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365* "Surface mount reflow soldering description".

#### 15.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

#### 15.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

#### 15.3 Wave soldering

Key characteristics in wave soldering are:

TJF1051

#### **High-speed CAN transceiver**

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

#### 15.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 7</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with <a href="Table 9">Table 9</a> and <a href="Table 9">10</a>

Table 9. SnPb eutectic process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C) Volume (mm³)		
	< 350	≥ 350	
< 2.5	235	220	
≥ 2.5	220	220	

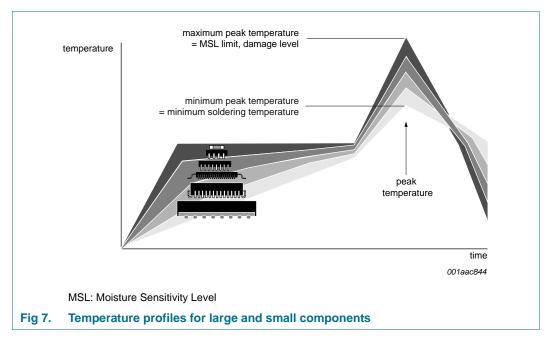
Table 10. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)			
	Volume (mm³)			
	< 350	350 to 2000	> 2000	
< 1.6	260	260	260	
1.6 to 2.5	260	250	245	
> 2.5	250	245	245	

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 7.

#### **High-speed CAN transceiver**



For further information on temperature profiles, refer to Application Note *AN10365* "Surface mount reflow soldering description".

## 16. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
TJF1051 v.3	20130208	Product data sheet	-	TJF1051 v.2		
Modifications:	Added TJF1051T variant					
	<ul> <li><u>Table 1</u>: deleted parameter T<sub>vj</sub></li> </ul>					
	<ul> <li><u>Table 5</u>: parameter value changed - T<sub>vj</sub></li> </ul>					
	<ul> <li><u>Table 6</u>: parameter value changed - R<sub>th(vj-a)</sub></li> </ul>					
	<ul> <li><u>Table 7</u>, <u>Table 8</u>: parameter value changed in table header- T<sub>amb</sub></li> </ul>					
	<ul> <li><u>Table 8</u>: parameter added in table header- V<sub>IO</sub></li> </ul>					
TJF1051 v.2	20110512	Product data sheet	-	TJF1051 v.1		
TJF1051 v.1	20100810	Product data sheet	-	-		

#### **High-speed CAN transceiver**

#### 17. Legal information

#### 18. Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 18.1 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 18.2 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

TJF1051

#### **High-speed CAN transceiver**

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

#### 18.3 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 19. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

**TJF1051 NXP Semiconductors** 

#### **High-speed CAN transceiver**

### 20. Contents

1	General description	. 1
2	Features and benefits	. 1
2.1	General	. 1
2.2	Low-power management	
2.3	Protection	
3	Quick reference data	
4	Ordering information	. 2
5	Block diagram	. 3
6	Pinning information	. 4
6.1	Pinning	. 4
6.2	Pin description	
7	Functional description	. 5
7.1	Operating modes	. 5
7.1.1	Normal mode	. 5
7.1.2	Silent mode	
7.2	Fail-safe features	
7.2.1	TXD dominant time-out function	
7.2.2	Internal biasing of TXD and S input pins	
7.2.3	Undervoltage detection on pins $V_{CC}$ and $V_{IO}$ .	
7.2.4 7.3	Overtemperature protection	
/ .3	Vi∩ SUDDIV DIN (TJFTU5TT/3)	. 6
8	Limiting values	. 6
8 9	Limiting values  Thermal characteristics	. 6 . 6
8 9 10	Limiting values	. 6 . 6 . 7
8 9	Limiting values	. 6 . 6 . 7
8 9 10	Limiting values	. 6 . 6 . 7
8 9 10 11	Limiting values	. 6 . 6 . 7 . 9
8 9 10 11 12	Limiting values	. 6 . 6 . 7 . 9
8 9 10 11 12 13	Limiting values	. 6 . 7 . 9 10
8 9 10 11 12 13	Limiting values. Thermal characteristics Static characteristics. Dynamic characteristics Application information. Package outline Handling information.	. 6 . 7 . 9 10 11
8 9 10 11 12 13 14	Limiting values	. 6 . 7 . 9 10 11 12
8 9 10 11 12 13 14 15	Limiting values. Thermal characteristics Static characteristics.  Dynamic characteristics Application information.  Package outline Handling information.  Soldering of SMD packages Introduction to soldering Wave and reflow soldering Wave soldering.	. 6 . 7 . 9 10 11 12 12
8 9 10 11 12 13 14 15 15.1 15.2	Limiting values. Thermal characteristics Static characteristics. Dynamic characteristics Application information. Package outline Handling information. Soldering of SMD packages Introduction to soldering Wave and reflow soldering.	. 6 . 7 . 9 10 11 12 12 12 12
8 9 10 11 12 13 14 15 15.1 15.2 15.3	Limiting values. Thermal characteristics Static characteristics.  Dynamic characteristics Application information.  Package outline Handling information.  Soldering of SMD packages Introduction to soldering Wave and reflow soldering Wave soldering.	. 6 . 7 . 9 10 11 12 12 12 12
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4	Limiting values. Thermal characteristics Static characteristics. Dynamic characteristics Application information. Package outline Handling information. Soldering of SMD packages Introduction to soldering. Wave and reflow soldering. Wave soldering. Reflow soldering.	. 6 . 7 . 9 10 11 12 12 12 13
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4 16	Limiting values. Thermal characteristics Static characteristics. Dynamic characteristics. Application information. Package outline Handling information. Soldering of SMD packages Introduction to soldering. Wave and reflow soldering. Wave soldering. Reflow soldering. Revision history.	. 6 . 7 . 9 10 11 12 12 12 13 14 15 15
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4 16 17	Limiting values. Thermal characteristics Static characteristics. Dynamic characteristics Application information. Package outline Handling information. Soldering of SMD packages Introduction to soldering Wave and reflow soldering Wave soldering. Reflow soldering. Reflow soldering. Revision history. Legal information.	. 6 . 7 . 9 10 11 12 12 12 13 14 15
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4 16 17 18 18.1 18.2	Limiting values. Thermal characteristics Static characteristics.  Dynamic characteristics Application information. Package outline Handling information.  Soldering of SMD packages Introduction to soldering. Wave and reflow soldering. Wave soldering. Reflow soldering. Reflow soldering. Revision history.  Legal information. Data sheet status Definitions. Disclaimers.	. 6 . 7 . 9 10 11 12 12 12 13 14 15 15
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4 16 17 18 18.1	Limiting values. Thermal characteristics Static characteristics.  Dynamic characteristics Application information.  Package outline Handling information.  Soldering of SMD packages Introduction to soldering. Wave and reflow soldering. Wave soldering. Reflow soldering. Reflow soldering. Revision history.  Legal information.  Data sheet status Definitions. Disclaimers Trademarks.	. 6 . 7 . 9 10 11 12 12 12 13 14 15 15
8 9 10 11 12 13 14 15 15.1 15.2 15.3 15.4 16 17 18 18.1 18.2	Limiting values. Thermal characteristics Static characteristics.  Dynamic characteristics Application information. Package outline Handling information.  Soldering of SMD packages Introduction to soldering. Wave and reflow soldering. Wave soldering. Reflow soldering. Reflow soldering. Revision history.  Legal information. Data sheet status Definitions. Disclaimers.	. 6 . 7 . 9 10 11 12 12 12 13 14 15 15 15

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

Document identifier: TJF1051